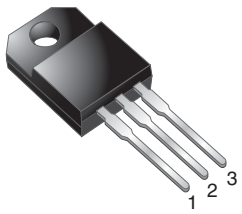
Dual High-Voltage Trench MOS Barrier Schottky Rectifier

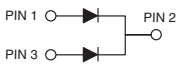
Ultra Low V_F = 0.36 V at I_F = 5 A

TMBS®

ITO-220AB



VF60100C



PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 30 A
V_{RRM}	100 V
I_{FSM}	320 A
V_F at I_F = 30 A	0.66 V
T_J max.	150 °C
Package	ITO-220AB
Circuit configuration	Common cathode

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT
HALOGEN FREE

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: ITO-220AB
Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102
M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T_A = 25 °C unless otherwise noted)

PARAMETER		SYMBOL	VF60100C	UNIT
Maximum repetitive peak reverse voltage		V_{RRM}	100	V
Maximum average forward rectified current (fig. 1)	per device	$I_{F(AV)}$	60	A
	per diode		30	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I_{FSM}	320	A
Isolation voltage from terminal to heatsink t = 1 min		V_{AC}	1500	V
Voltage rate of change (rated V_R)		dV/dt	10 000	V/µs
Operating junction and storage temperature range		T_J, T_{STG}	-40 to +150	°C

ELECTRICAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)						
PARAMETER	**TEST CONDITIONS**		**SYMBOL**	**TYP.**	**MAX.**	**UNIT**
Instantaneous forward voltage per diode	I_F = 5 A	T_A = 25 °C	V_F (1)	0.45	-	V
	I_F = 10 A			0.52	-	
	I_F = 15 A			0.58	0.63	
	I_F = 20 A			0.63	-	
	I_F = 30 A			0.73	0.79	
	I_F = 5 A	T_A = 125 °C		0.36	-	
	I_F = 10 A			0.45	-	
	I_F = 15 A			0.53	0.58	
	I_F = 20 A			0.58	-	
	I_F = 30 A			0.66	0.70	
Reverse current at rated V_R per diode	V_R = 80 V	T_A = 25 °C	I_R (2)	24	500	µA
		T_A = 125 °C		13	20	mA
	V_R = 100 V	T_A = 25 °C		65	1000	µA
		T_A = 125 °C		30	-	mA

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)				
PARAMETER		**SYMBOL**	**VF60100C**	**UNIT**
Typical thermal resistance	per diode	$R_{\theta JC}$	5.0	°C/W
	per device		3.5	

ORDERING INFORMATION (Example)					
PACKAGE	**PREFERRED P/N**	**UNIT WEIGHT (g)**	**PACKAGE CODE**	**BASE QUANTITY**	**DELIVERY MODE**
ITO-220AB	VF60100C-M3/4W	1.76	4W	50/tube	Tube

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

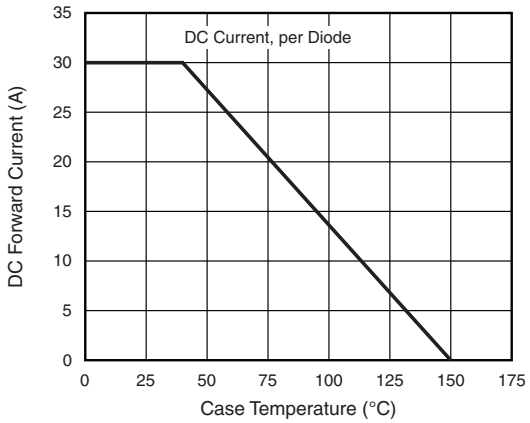


Fig. 1 - Maximum Forward Current Derating Curve

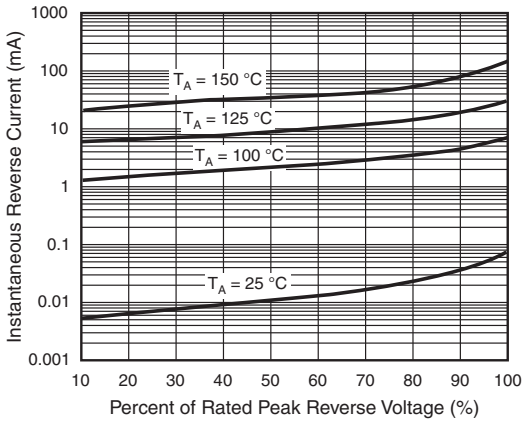


Fig. 4 - Typical Reverse Characteristics Per Diode

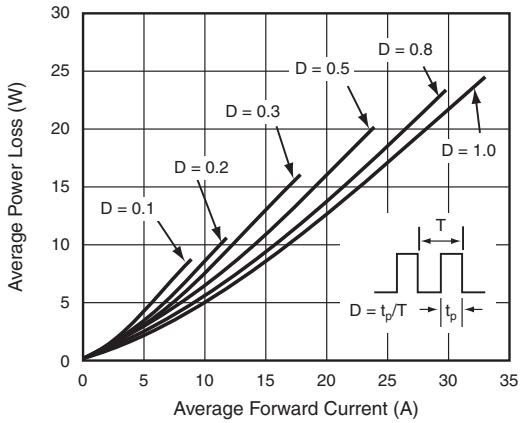


Fig. 2 - Forward Power Loss Characteristics Per Diode

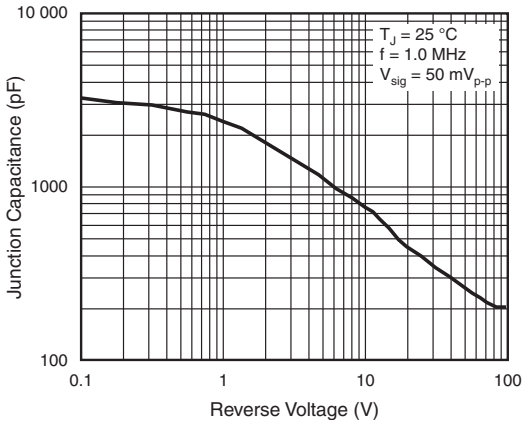


Fig. 5 - Typical Junction Capacitance Per Diode

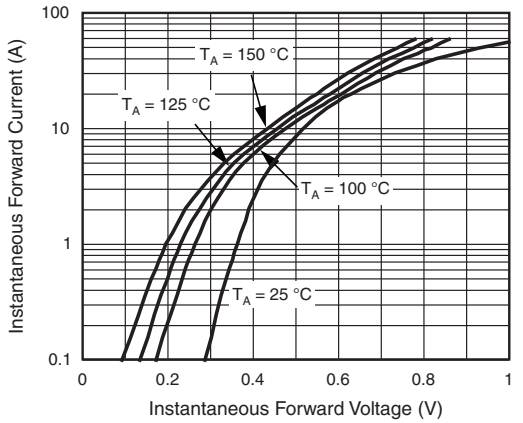
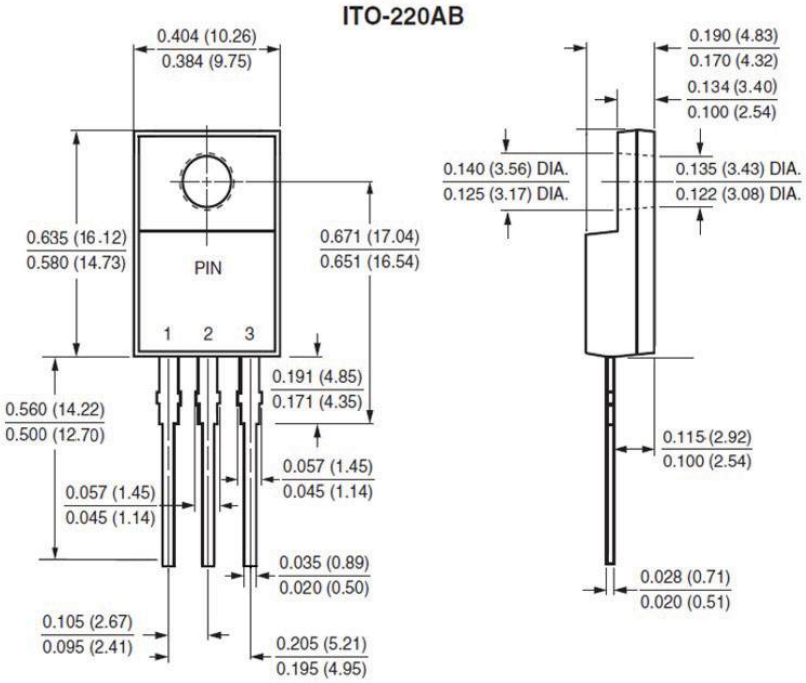


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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